

MITSUBISHI THYRISTOR MODULES

TM90RZ/EZ-24,-2H

HIGH VOLTAGE HIGH POWER GENERAL USE
INSULATED TYPE

TM90RZ/EZ-24,-2H



- **IT (AV)** Average on-state current **90A**
- **IF (AV)** Average forward current **90A**
- **VRRM** Repetitive peak reverse voltage
..... **1200/1600V**
- **VDRM** Repetitive peak off-state voltage
..... **1200/1600V**
- **MIX DOUBLE ARMS**
- **Insulated Type**
- **UL Recognized**

Yellow Card No. E80276 (N)

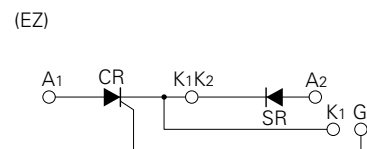
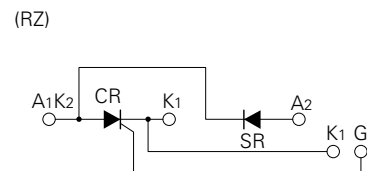
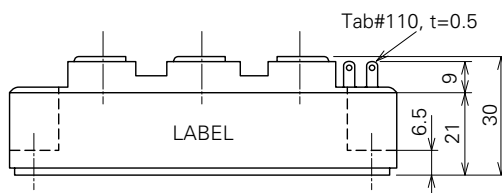
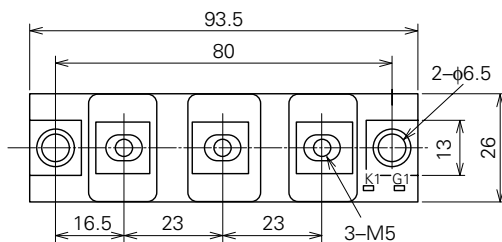
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APPLICATION

DC motor control, NC equipment, AC motor control, contactless switches,
electric furnace temperature control, light dimmers

OUTLINE DRAWING & CIRCUIT DIAGRAM

Dimensions in mm



TM90RZ/EZ-24,-2H**HIGH VOLTAGE HIGH POWER GENERAL USE****INSULATED TYPE****ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Voltage class		Unit
		24	2H	
VRRM	Repetitive peak reverse voltage	1200	1600	V
VRSM	Non-repetitive peak reverse voltage	1350	1700	V
VR (DC)	DC reverse voltage	960	1280	V
VDRM	Repetitive peak off-state voltage	1200	1600	V
VDSM	Non-repetitive peak off-state voltage	1350	1700	V
VD (DC)	DC off-state voltage	960	1280	V

Symbol	Parameter	Conditions	Ratings	Unit
IT (RMS), IF (RMS)	RMS current		140	A
IT (AV), IF (AV)	Average current	Single-phase, half-wave 180° conduction, Tc=82°C	90	A
ITSM, IFSM	Surge (non-repetitive) current	One half cycle at 60Hz, peak value	1800	A
I ² t	I ² t for fusing	Value for one cycle of surge current	1.4 × 10 ⁴	A ² s
di/dt	Critical rate of rise of on-state current	V _D =1/2V _{DRM} , I _G =1.0A, T _j =125°C	100	A/μs
PGM	Peak gate power dissipation		5.0	W
PG (AV)	Average gate power dissipation		0.5	W
VFGM	Peak gate forward voltage		10	V
VRGM	Peak gate reverse voltage		5.0	V
IFGM	Peak gate forward current		2.0	A
T _j	Junction temperature		-40~125	°C
T _{stg}	Storage temperature		-40~125	°C
V _{iso}	Isolation voltage	Charged part to case	2500	V
—	Mounting torque	Main terminal screw M5	1.47~1.96	N·m
			15~20	kg·cm
		Mounting screw M6	1.96~2.94	N·m
			20~30	kg·cm
—	Weight	Typical value	160	g

ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
IRRM	Repetitive peak reverse current	T _j =125°C, VRRM applied	—	—	15	mA
IDRM	Repetitive peak off-state current	T _j =125°C, VDRM applied	—	—	15	mA
VTM, VFM	Forward voltage	T _j =125°C, I _{TM} =I _{FM} =270A, instantaneous meas.	—	—	1.4	V
dv/dt	Critical rate of rise of off-state voltage	T _j =125°C, V _D =2/3V _{DRM}	500	—	—	V/μs
VGT	Gate trigger voltage	T _j =25°C, V _D =6V, R _L =2Ω	—	—	2.0	V
VGD	Gate non-trigger voltage	T _j =125°C, V _D =1/2V _{DRM}	0.25	—	—	V
IGT	Gate trigger current	T _j =25°C, V _D =6V, R _L =2Ω	15	—	100	mA
R _{th} (j-c)	Thermal resistance	Junction to case (per 1/2 module)	—	—	0.3	°C/W
R _{th} (c-f)	Contact thermal resistance	Case to fin, conductive grease applied (per 1/2 module)	—	—	0.2	°C/W
—	Insulation resistance	Measured with a 500V megohmmeter between main terminal and case	10	—	—	MΩ

Note: Items of the above table applies to the Thyristor part and the Diode part as circled in the following tables.

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MAXIMUM RATINGS

Item	VRRM	VRSM	VR (DC)	VDRM	VDSM	VD (DC)	IT (RMS)	IT (AV)	ITSM	i^2t	di/dt
							IF (RMS)	IF (AV)	IFSM		
Thyristor	○	○	○	○	○	○	○	○	○	○	○
Diode	○	○	○	—	—	—	○	○	○	○	—

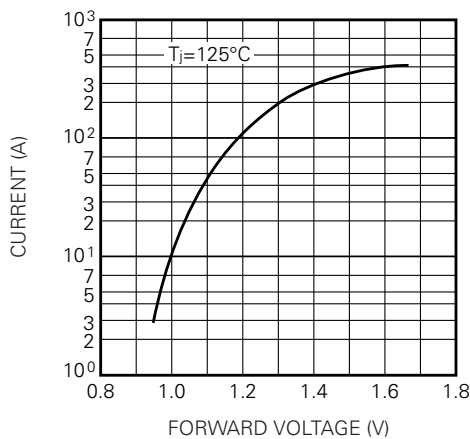
Item	PGM	PG (AV)	VFGM	IFGM	T _j	T _{stg}
Thyristor	○	○	○	○	○	○
Diode	—	—	—	—	○	○

ELECTRICAL CHARACTERISTICS

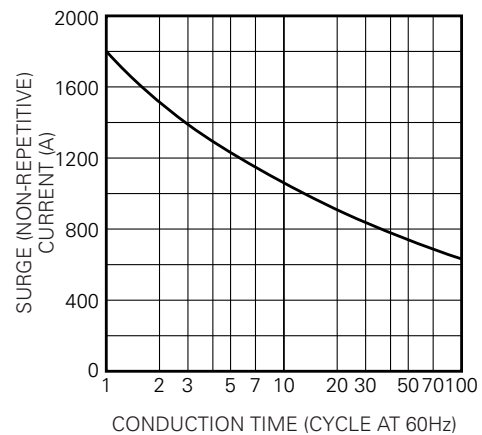
Item	IRRM	IDRM	V _{TM}	dv/dt	V _{GT}	V _{GD}	I _{GT}	R _{th} (j-c)	R _{th} (c-f)
			V _{FM}						
Thyristor	○	○	○	○	○	○	○	○	○
Diode	○	—	○	—	—	—	—	○	○

PERFORMANCE CURVES

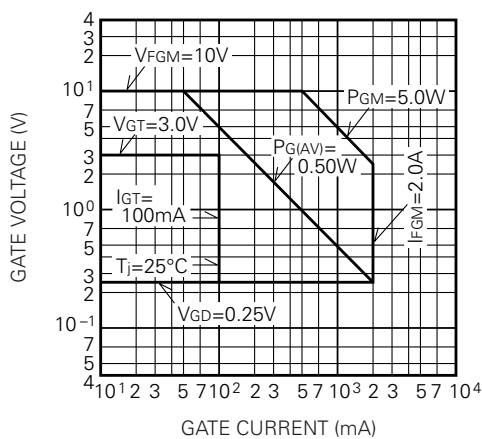
MAXIMUM FORWARD CHARACTERISTIC



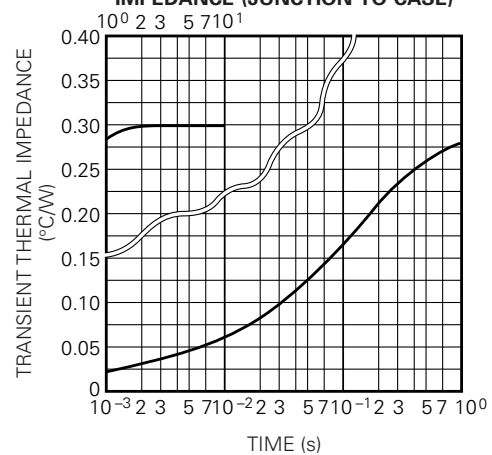
RATED SURGE (NON-REPETITIVE) CURRENT



GATE CHARACTERISTICS



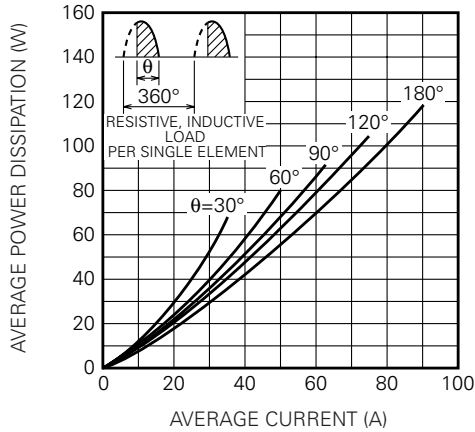
MAXIMUM TRANSIENT THERMAL IMPEDANCE (JUNCTION TO CASE)



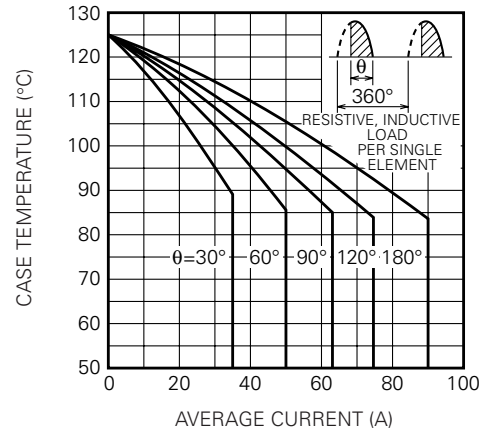
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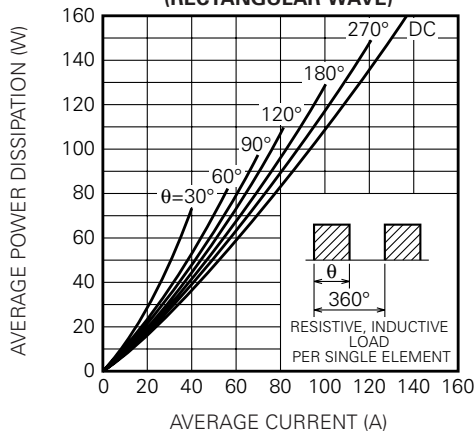
MAXIMUM AVERAGE POWER DISSIPATION (SINGLE PHASE HALF WAVE)



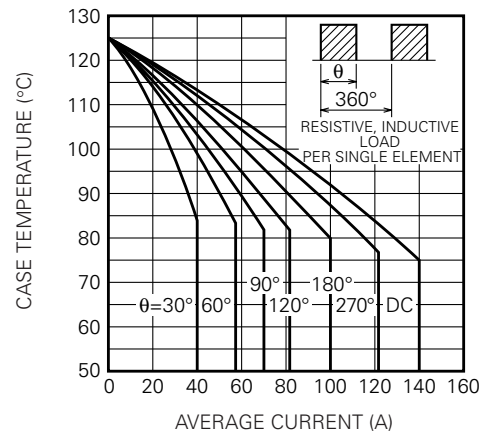
LIMITING VALUE OF THE AVERAGE CURRENT (SINGLE PHASE HALF WAVE)



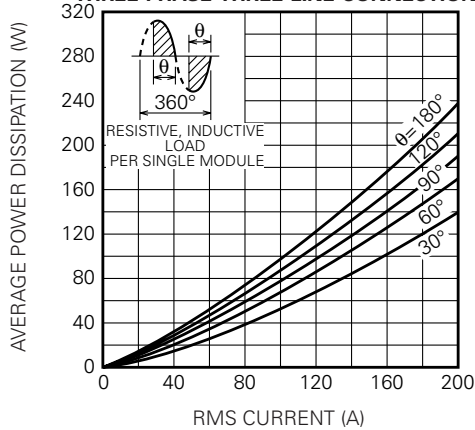
MAXIMUM AVERAGE POWER DISSIPATION (RECTANGULAR WAVE)



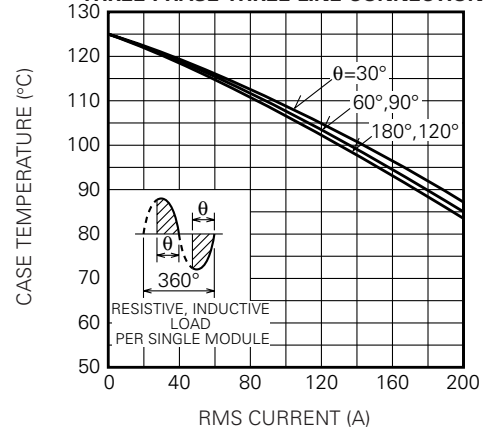
LIMITING VALUE OF THE AVERAGE CURRENT (RECTANGULAR WAVE)



MAXIMUM AVERAGE POWER DISSIPATION (REVERSE-PARALLEL CONNECTION, THREE-PHASE THREE-LINE CONNECTION)



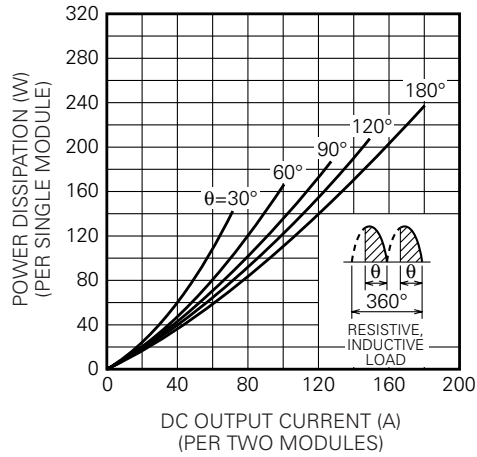
LIMITING VALUE OF THE RMS CURRENT (REVERSE-PARALLEL CONNECTION, THREE-PHASE THREE-LINE CONNECTION)



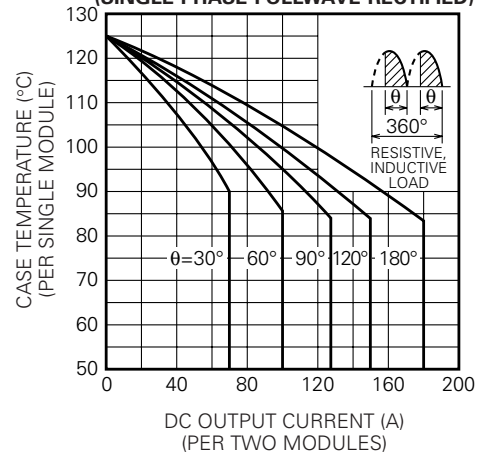
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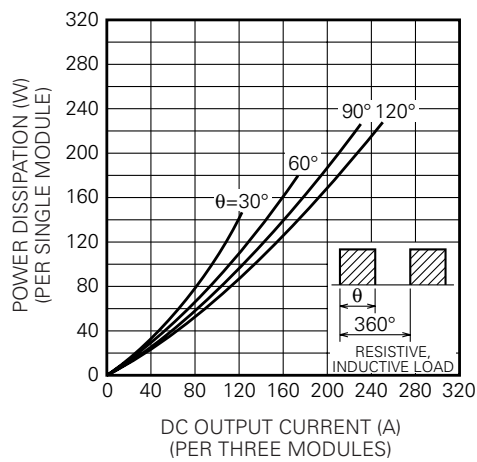
**MAXIMUM POWER DISSIPATION
(SINGLE PHASE FULLWAVE RECTIFIED)**



**LIMITING VALUE OF
THE DC OUTPUT CURRENT
(SINGLE PHASE FULLWAVE RECTIFIED)**



**MAXIMUM POWER DISSIPATION
(THREE-PHASE FULLWAVE RECTIFIED)**



**LIMITING VALUE OF THE DC
OUTPUT CURRENT
(THREE-PHASE FULLWAVE RECTIFIED)**

